October 1987 Revised March 2002

CD4007C Dual Complementary Pair Plus Inverter

General Description

FAIRCHILD

SEMICONDUCTOR

The CD4007C consists of three complementary pairs of Nand P-channel enhancement mode MOS transistors suitable for series/shunt applications. All inputs are protected from static discharge by diode clamps to V_{DD} and V_{SS}.

For proper operation the voltages at all pins must be constrained to be between V_{SS} – 0.3V and V_{DD} + 0.3V at all times.

Ordering Code:

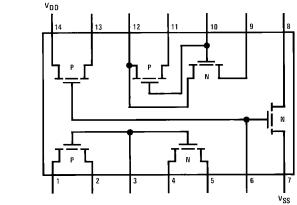
	-	-			
Order Number	Package Number	Package Description			
CD4007CM	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow			
CD4007CN N14A 14-Lead Plastic Dual-In-		14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide			
Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.					

Features

■ Wide supply voltage range: 3.0V to 15V

■ High noise immunity: 0.45 V_{CC} (typ.)

Connection Diagram



Note: All P-channel substrates are connected to V_{DD} and all N-channel substrates are connected to V_{SS} .

Top View

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Absolute Maximum Ratings(Note 1)

Voltage at Any Pin	V_{SS} –0.3V to V_{DD} +0.3V
Operating Temperature Range	-55°C to +125°C
Storage Temperature Range	-65°C to +150°C
Power Dissipation (P _D)	
Dual-In-Line	700 mW
Small Outline	500 mW
Operating V _{DD} Range	$\rm V_{SS}$ +3.0V to $\rm V_{SS}$ +15V
Lead Temperature	
(Soldering, 10 seconds)	260°C

Note 1: This device should not be connected to circuits with the power on because high transient voltages may cause permanent damage.

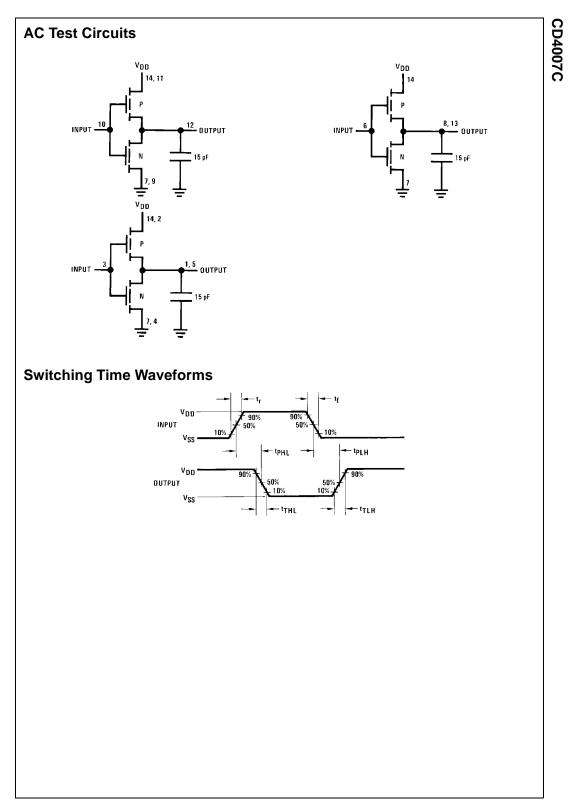
DC Electrical Characteristics

			Limits										
Symbol	Parameter	Conditions	–55°C		+25°C			+125°C			Units		
			Min	Тур	Max	Min	Тур	Max	Min	Тур	Max		
IL.	Quiescent Device	$V_{DD} = 5.0V$			0.05		0.001	0.05			3.0	μA	
	Current	$V_{DD} = 10V$			0.1		0.001	1.0			6.0	μА	
PD	Quiescent Device	$V_{DD} = 5.0V$			0.25		0.005	2.5			15	μW	
	Dissipation Package	$V_{DD} = 10V$			1.0		0.001	10			60	μνν	
V _{OL}	Output Voltage	$V_{DD} = 5.0V$			0.05		0	0.01			0.05	v	
	LOW Level	$V_{DD} = 10V$			0.05		0	0.01			0.05	v	
V _{OH}	Output Voltage	$V_{DD} = 5.0V$	4.95			4.95	5.0		4.95			v	
	HIGH Level	$V_{DD} = 10V$	9.95			9.95	10		9.95			v	
V _{NL}	Noise Immunity	$V_{DD} = 5.0V, V_{O} = 3.6V$			1.5		2.25	1.5			1.4	v	
	(All inputs)	$V_{DD} = 10V, V_{O} = 7.2V$			3.0		4.5	3.0			2.9	v	
V _{NH}	Noise Immunity	$V_{DD} = 5.0V, V_{O} = 0.95V$	3.6			3.5	2.25		3.5			v	
	(All Inputs)	$V_{DD} = 10V, V_{O} = 2.9V$	7.1			7.0	4.5		7.0			v	
I _D N	Output Drive Current	$V_{DD} = 5.0V, V_{O} = 0.4V, V_{I} = V_{DD}$	0.75			0.6	1.0		0.4			mA	
	N-Channel	$V_{DD}=10V,\ V_O=0.5V,\ V_I=V_{DD}$	1.6			1.3	2.5		0.95			mA	
I _D P	Output Drive Current	$V_{DD} = 5.0$ V, $V_{O} = 2.5$ V, $V_{I} = V_{SS}$	-1.75			-1.4	-4.0		-1.0			mA	
	P-Channel	$V_{DD} = 10V, \ V_O = 9.5V, \ V_I = V_{SS}$	-1.35			-1.1	-2.5		-0.75			IIIA	
Ц	Input Current						10					pА	

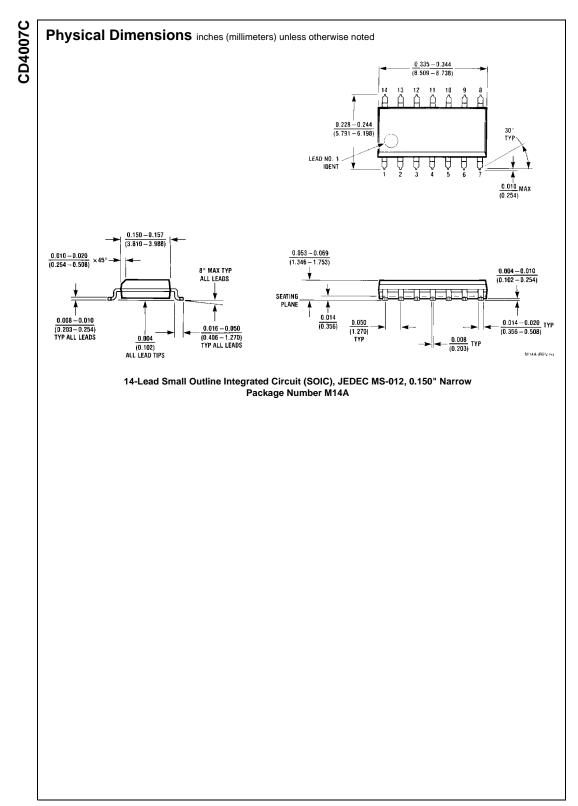
AC Electrical Characteristics (Note 2)

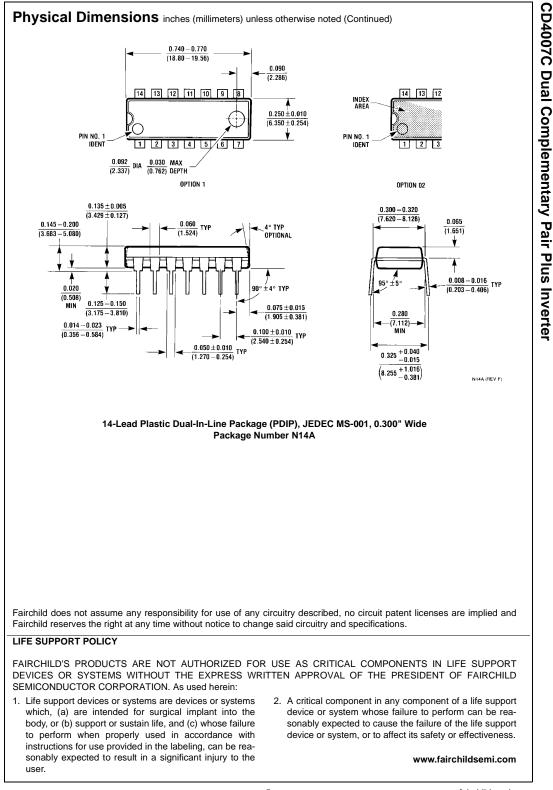
Symbol	Parameter	Conditions	Min	Тур	Max	Units
t _{PLH} = t _{PHL}	Propagation Delay Time	V _{DD} = 5.0V		35	75	ns
		$V_{DD} = 10V$		20	50	
t _{TLH} = t _{THL}	Transition Time	V _{DD} = 5.0V		50	100	ns
		$V_{DD} = 10V$		30	50	
CI	Input Capacitance	Any Input		5		pF

Note 2: AC Parameters are guaranteed by DC correlated testing.



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